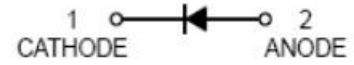


SOD-323 Switching Diode 开关二极管



■Features 特点

Fast Switching Speed 快的开关速度

Surface mount device 表面贴装器件

High Conductance 高电导率

Case 封装:SOD-323

Marking 印字: T4

■Maximum Rating 最大额定值

($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

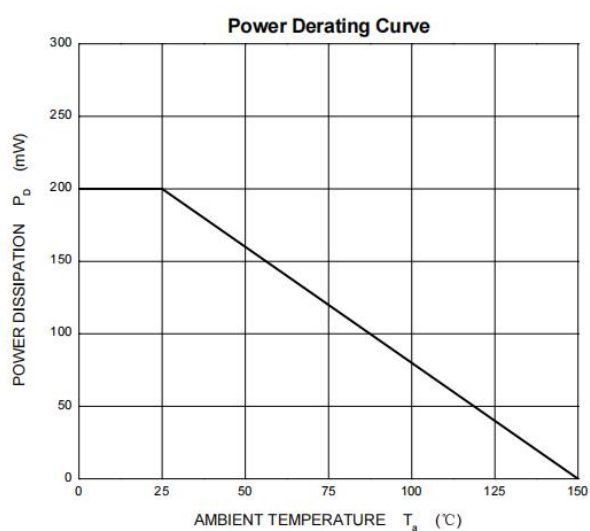
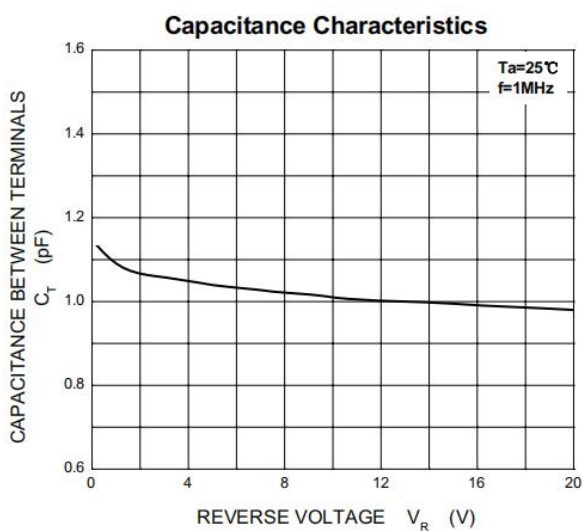
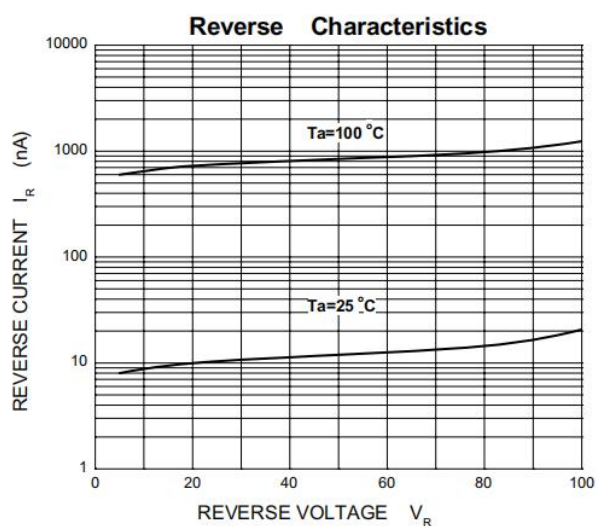
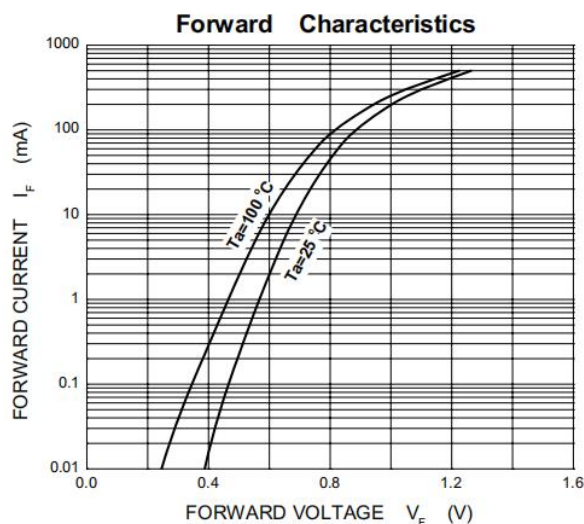
Characteristic 特性参数	Symbol 符号	Rating 额定值	Unit 单位
DC Reverse Voltage 直流反向电压	V_R	100	V
Peak Repetitive Reverse Voltage 峰值重复反向电压	V_{RRM}	100	V
RMS Reverse Voltage 反向电压均方根值	$V_{R(RMS)}$	70	V
Forward Rectified Output Current 正向工作电流	I_O	150	mA
Non-Repetitive Peak Surge Current@ $t=1\mu\text{s}$ 不重复峰值浪涌电流@ $t=1\text{s}$	I_{FSM}	2 1	A
Power Dissipation 耗散功率	P_D	200	mW
Thermal Resistance Junction-Ambient 结到环境热阻	$R_{\theta JA}$	625	$^{\circ}\text{C}/\text{W}$
Junction/Storage Temperature 结温/储藏温度	T_J, T_{stg}	$-50\text{to}+150^{\circ}\text{C}$	$^{\circ}\text{C}$

■Electrical Characteristics 电特性

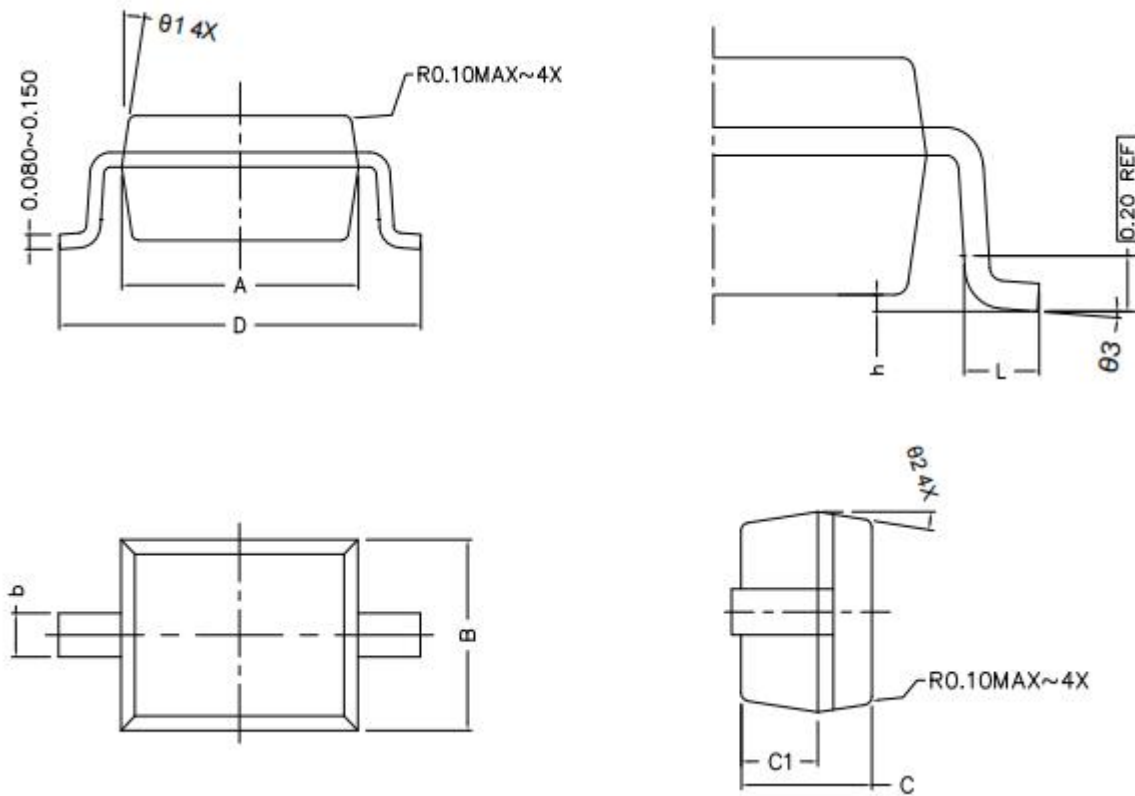
($T_A=25^{\circ}\text{C}$ unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Max 最大值	Unit 单位	Condition 条件
Reverse Voltage 反向电压	V_R	100		V	$I_R=1\mu\text{A}$
Forward Voltage 正向电压	V_F		0.85 1.0 1.25	V	$I_F=10\text{mA}$ $I_F=50\text{mA}$ $I_F=150\text{mA}$
Reverse Current 反向电流	I_R		25 1	nA μA	$V_R=20\text{V}$ $V_R=100\text{V}$
Revers Recovery Time 反向恢复时间	T_{rr}		4	nS	$I_{rr}=0.1 \cdot I_R$, $I_F=I_R=10\text{mA}$, $R_L=100\Omega$
Junction Capacitance 结电容	C_J		1.15	pF	$V_R=4\text{V}$, $f=1\text{MHz}$

■ Typical Characteristic Curve 典型特性曲线



■ Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.600	1.800	0.063	0.071
B	1.200	1.400	0.047	0.055
C	0.750	0.950	0.030	0.037
C1	0.450	0.550	0.018	0.022
D	2.450	2.800	0.096	0.110
L	0.200	0.400	0.008	0.016
b	0.200	0.400	0.008	0.016
h	0.020	0.120	0.001	0.005
⊖ 3	0°	8°	0°	8°